

isc N-Channel MOSFET Transistor

IRF540FI

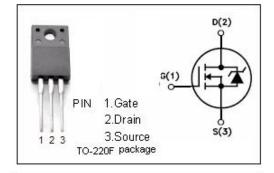
FEATURES

- Low R_{DS(on)}
- V_{GS} Rated at ±20V
- · Silicon Gate for Fast Switching Speed
- Rugged
- · Low Drive Requirements
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION



 Designed especially for high voltage, high speed applications, such as off-line switching power supplies, UPS,AC and DC motor controls, relay and solenoid drivers.

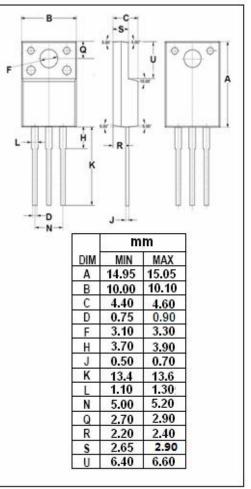


• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	100	V
V _{GS}	Gate-Source Voltage-Continuous ±		V
I _D	Drain Current-Continuous 16		Α
I _{DM}	Drain Current-Single Plused	120	Α
P_D	Total Dissipation @T _C =25°C 45		W
Tj	Max. Operating Junction Temperature -55~150		$^{\circ}$
T _{stg}	Storage Temperature -55~150		$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	1.0	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient		°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	100		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 15A		0.077	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±500	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 100V; V _{GS} =0		250	uA
V _{SD}	Forward On-Voltage	I _S = 16A; V _{GS} =0		2.5	V

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